NSN 5961-01-008-9641

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Metal Overall Length: Between 0.065 inches and 0.085 inches Terminal Length: 0.500 inches Overall Diameter: Between 0.209 inches and 0.230 inches Internal Configuration: Junction contact Electrode Internally-electrically Connected To Case: Collector Mounting Method: Terminal Terminal Features Provided: Hermetically sealed case Semiconductor Material: Silicon Voltage Rating In Volts Per Characteristic: 50.0 breakdown voltage, collector-to-base, emitter open and 30.0 breakdown voltage, collector-to-emit	
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voltage emitter-to-base collector open	tter, base open and 5.0 breakdown
Current Rating Per Characteristic:	
1.50 amperes source cutoff current	
Power Rating Per Characteristic:	
500.0 milliwatts small-signal input power, common-collector	
Special Features:	
Junction pattern arrangement: npn	
Terminal Type And Quantity:	
3 uninsulated wire lead	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
A110a0	